NSN 5961-01-283-9040

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View Online at https://aerobasegroup.com/nsn/5961-01-283-9040 **Inclosure Material:** Metal **Overall Length:** 0.210 inches **Terminal Length:** 0.500 inches **Overall Diameter:** 0.195 inches **Internal Configuration:** Junction contact Joint Electronic Device Engineering Council/jedec/case Outline Designation: To-72 **Electrode Internally-electrically Connected To Case:** Collector **Mounting Method: Terminal Terminal Circle Diameter:** 0.110 inches **Features Provided:** Hermetically sealed case **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: -15.0 collector to base voltage/static/emitter open and -15.0 collector to emitter voltage/static/base open and -4.5 emitter to base voltage, static, collector open **Current Rating Per Characteristic:** -30.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 200.0 milliwatts small-signal input power, common-collector absolute **Transfer Ratio:** 25.0 static forward current transfer ratio, common-emitter **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius ambient air **Special Features:** Junction pattern arrangement: pnp **Terminal Type And Quantity:** 4 uninsulated wire lead Shelf Life:

No

N/a

Unit Of Measure:

Demilitarization:

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